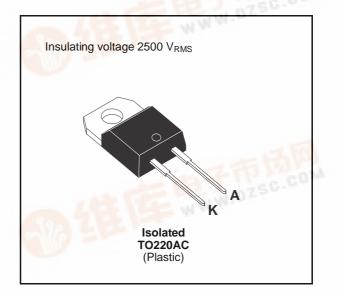
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FAST RECOVERY RECTIFIER DIODE

- VERY HIGH REVERSE VOLTAGE CAPABILITY
- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING
- INSULATED: Capacitance 7pF



SUITABLE APPLICATIONS

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS DZSC.COM
- RECTIFIER IN S.M.P.S.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive Peak Reverse Voltage	1000	V	
V _{RSM}	Non Repetitive Peak Reverse Voltage	15	1000	V
I _{FRM}	Repetive Peak Forward Current	ward Current t _p ≤ 10µs		А
I _{F (RMS)}	RMS Forward Current	25	А	
I _{F (AV)}	Average Forward Current	$T_{c} = 50^{\circ}C$ $\delta = 0.5$	12	А
I _{FSM}	Surge non Repetitive Forward Current t _p = 10ms Sinusoidal		75	А
Р	Power Dissipation	Power Dissipation $T_c = 50^{\circ}C$		W
T _{stg} Tj	Storage and Junction Temperature Range	- 40 to + 150 - 40 to + 150	°C	

THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
R _{th (j} - c)	Junction-case	4	°C/W



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ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Synbol	Test Conditions			Тур.	Max.	Unit
I _R	T _j = 25°C	$V_{R} = V_{RRM}$			50	μΑ
	T _j = 100°C				2.5	mA
V _F	T _j = 25°C	I _F = 12A			1.9	V
	$T_j = 100^{\circ}C$				1.8	

RECOVERY CHARACTERISTICS

Symbol	Test Conditions					Тур.	Max.	Unit
t _{rr}	$T_j = 25^{\circ}C$	$I_F = 1A$ $di_F/dt = -15A/\mu s$ $V_R = 3$		$V_R = 30V$			155	ns
		I _F = 0.5A	I _R = 1A	$I_{rr} = 0.25A$			65	

TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions			Тур.	Max.	Unit
t _{IRM}	di _F /dt = - 50A/µs	$V_{CC} = 200 V$ I _F = 12A			200	ns
	di _F /dt = - 100A/µs	L _p ≤ 0.05μH T _j = 100°C See figure 11		120		
I _{RM}	di _F /dt = -50A/µs				7.8	А
	di _F /dt = - 100A/µs			9		

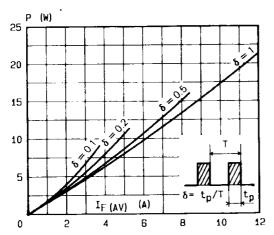
TURN-OFF OVERVOLTAGE COEFFICIENT (With Series Inductance)

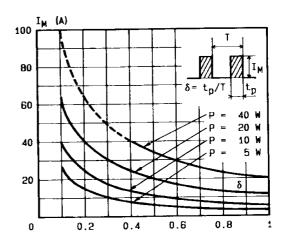
Symbol	Test Conditions				Тур.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	T _j = 100°C diϝ/dt = - 12A/μs	$V_{CC} = 200V$ $L_p = 12\mu H$	I _F = I _{F (AV)} See figure 12			4.5	

To evaluate the conduction losses use the following equations: $V_F = 1.47 + 0.026 I_F$ $P = 1.47 \times IF_{(AV)} + 0.026 I_F^2_{(RMS)}$

Figure 1. Low frequency power losses versus average current

Figure 2. Peak current versus form factor





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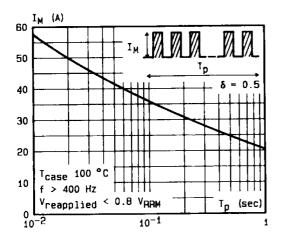
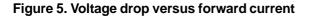


Figure 3. Non repetitive peak surge current versus overload duration



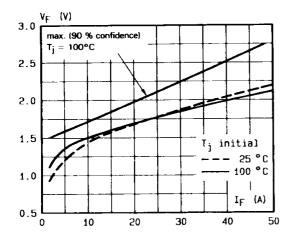
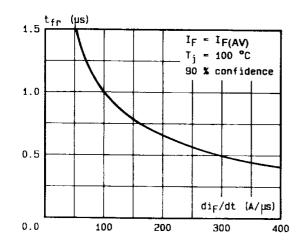


Figure 7. Recovery time versus di_F/d_{t-}



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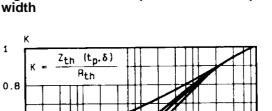


Figure 4. Thermal impedance versus pulse

0.8 0.6 0.4 0.2 (s) tp 0 10-2 10-1 10-3 1

Figure 6. Recovery charge versus di_F/d_{t-}

10

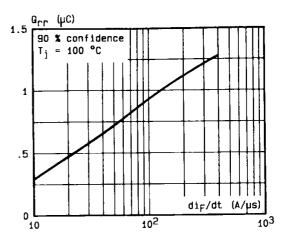
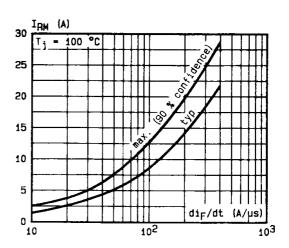


Figure 8. Peak reverse current versus di_F/dt-



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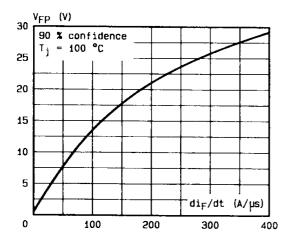


Figure 9. Peak forward voltage versus diF/dt-

Figure 11. Turn-off switching characteristics (without series inductance).

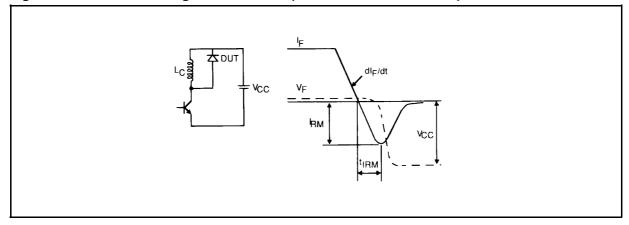
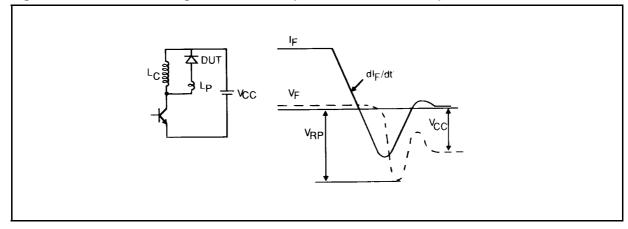
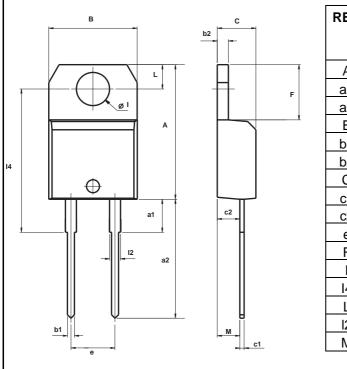


Figure 12. Turn-off switching characteristics (with series inductance)



PACKAGE MECHANICAL DATA : Isolated TO220AC Plastic



REF.	DIMENSIONS							
	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	15.20		15.90	0.598		0.625		
a1		3.75			0.147			
a2	13.00		14.00	0.511		0.551		
В	10.00		10.40	0.393		0.409		
b1	0.61		0.88	0.024		0.034		
b2	1.23		1.32	0.048		0.051		
С	4.40		4.60	0.173		0.181		
c1	0.49		0.70	0.019		0.027		
c2	2.40		2.72	0.094		0.107		
е	4.80		5.40	0.189		0.212		
F	6.20		6.60	0.244		0.259		
I	3.75		3.85	0.147		0.151		
14	15.80	16.40	16.80	0.622	0.646	0.661		
L	2.65		2.95	0.104		0.116		
12	1.14		1.70	0.044		0.066		
М		2.60			0.102			

- Marking: type number
- Cooling method: by conduction (method C)
- Weight : 1.86g
- Recommended torque value : 80cm. N
- Maximum torque value : 100cm. N

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